



# TECHNICAL INFORMATION

GOLD BONDED  
GERMANIUM DIODE

*Excellence in Electronics*

The IN308 is a germanium Gold Bonded junction diode of small size designed for switching applications requiring extreme stability, fast switching, high forward current and high ratio of back to forward resistance.

## MECHANICAL DATA

CASE: Metal and Glass

TERMINALS: Dumet wire tinned to within 1/8" of barrel  
Diameter: 0.017" max. Length: 1" min.

TERMINAL CONNECTIONS: White Band at Cathode Terminal

MOUNTING POSITION: Any

## ELECTRICAL DATA

RATINGS - ABSOLUTE MAXIMUM VALUES: (at 25° C)

Peak Inverse Voltage  
Continuous Inverse Voltage  
Average Rectified Current  
Peak Rectified Current  
Surge Current (for 1 sec.)  
Ambient Temperature Range  
Dissipations at:  
25 °C  
50 °C

10 volts  
8 volts  
100 ma.  
350 ma.  
500 ma.  
- 10 to + 70 °C

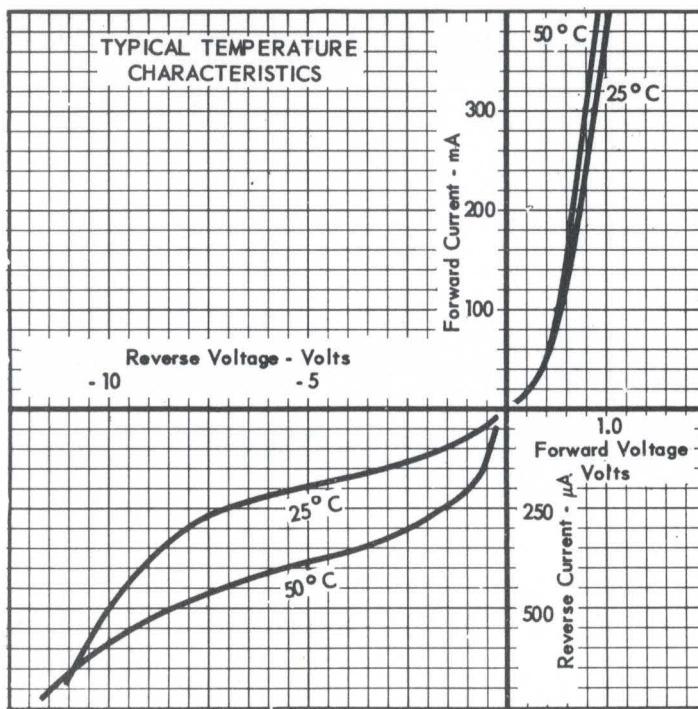
CHARACTERISTICS: (at 25° C)

Maximum Inverse Current at -8 volts  
Minimum Forward Current at +1 volt

55 °C

25 °C

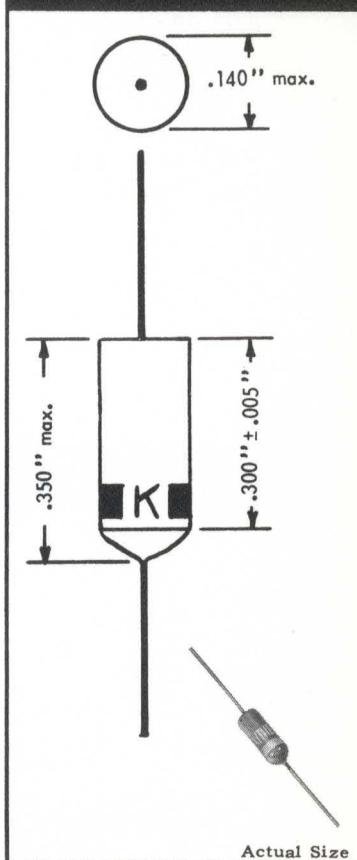
500 μa.  
300 ma.



Tentative Data

**TYPE**  
**1N308**

(CK741)



**RAYTHEON MANUFACTURING COMPANY**  
RECEIVING AND CATHODE RAY TUBE OPERATIONS